## NSN 5962-01-363-2465

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Maximum Power Dissipation Rating:
300.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmed and burn in, mil-std-883, class d
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Digital fused pal
Voltage Rating And Type Per Characteristic:
-0.5 volts absolute input and 12.0 volts absolute input and -1.5 volts absolute output and 12.0 volts absolute output
Memory Device Type:
Programmed
Hybrid Technology Type:
Monolithic
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0